

## GaN, High-Power Switches



RFMW, Ltd. announces design and sales support for TriQuint Semiconductor's high power RF switch family. Four models span frequencies up to 18GHz and power levels to 40W. These SPDT switches offer switching speeds <50nS and insertion loss <1.5dB. Targeting applications in military and civilian radar, EW, communications and test instrumentation, these GaN on SiC switches are available from stock at RFMW, Ltd.

[TGS2353](#) [1]: DC-18GHz, 10W power handling, DIE format.

[TGS2352](#) [2]: DC-12GHz, 20W power handling, DIE format.

[TGS2351](#) [3]: DC-6GHz, 40W power handling, DIE format

[TGS2351-SM](#) [4]: DC-6GHz, 40W power handling, QFN package.

### For more information please contact:

TriQuint Semiconductor Stocking Distributor

RFMW, Ltd.

[info@rfmw.com](mailto:info@rfmw.com) [5]

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### Links:

[1] <http://www.rfmw.com/PortalProductDetail.aspx?ProdId=423552>

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